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View Online at https://aerobasegroup.com/nsn/5961-01-173-3021 **Inclosure Material:** Plastic and metal **Overall Length:** 0.730 inches **Overall Height:** 0.612 inches **Overall Width:** 0.420 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-220aa **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 75.0 collector to base voltage/static/emitter open and 5.0 emitter to base voltage, static, collector open and 65.0 collector-to-emitter, resistance between base and emitter **Current Rating Per Characteristic:** 7.00 amperes source cutoff current and 3.00 amperes source cutoff current **Power Rating Per Characteristic:** 50.0 watts small-signal input power, common-collector preset **Transfer Ratio:** 100.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 pin **Specification Data:** 80131-release6145a professional/industrial association specification Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

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